TOSHIBA SUPER FAST RECOVERY RECTIFIER SILICON DIFFUSED TYPE

3 G U 4 1

SWITCHING TYPE POWER SUPPLY APPLICATIONS

 $: V_{RRM} = 100 \sim 400 V$ Repetitive Peak Reverse Voltage

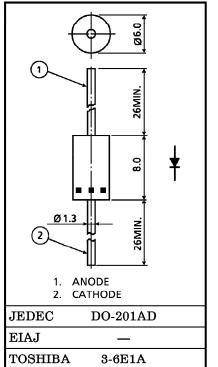
 $: I_{F(AV)} = 3.0A$ Average Forward Current

Very Fast Reverse-Recovery Time $: t_{rr} = 100 ns$

MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Repetitive Peak Reverse Voltage	v_{RRM}	400	V	
Average Forward Current	I _{F (AV)}	3.0	A	
Peak One Cycle Surge Forward	Incre	80 (50Hz)	A	
Current (Non-Repetitive)	I _{FSM}	88 (60Hz)		
Junction Temperature	$\mathrm{T_{j}}$	-40~150	$^{\circ}\mathrm{C}$	
Storage Temperature Range	$\mathrm{T_{stg}}$	-40~150	$^{\circ}\mathrm{C}$	

Unit in mm



Weight: 1.18g

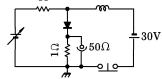
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Peak Forward Voltage	$v_{ m FM}$	$I_{\text{FM}} = 3.0 \text{A}$	_	_	1.5	V
Repetitive Peak Reverse Current	${ m I}_{ m RRM}$	$V_{ m RRM} = 400 V$	_	_	300	μ A
Reverse Recovery Time (Note 1)	${ m t_{rr}}$	$I_F = 1A$, di/dt = $-30A/\mu s$	_	_	100	ns
Forward Recovery Time (Note 2)	${ m t_{fr}}$	$I_{ m F}$ = 1.0A	_	_	200	ns
Thermal Resistance (Note 3)	$R_{ ext{th }(j-a)}$	Junction to Ambient	_	_	37	°C/W
Thermal Resistance (Note 4)	$\mathrm{R}_{\mathrm{th}(\mathrm{j-}\ell)}$	Junction to Lead	_	_	12	°C/W

Note 1: t_{rr} TEST CIRCUIT

WAVEFORM

 $I_F = 1.0A$



 $di/dt = -30A/\mu s$

10%· IRP

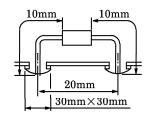
INPUT °

WAVEFORM $1.1 \times V_F$ tfr

Note 2: tfr TEST CIRCUIT

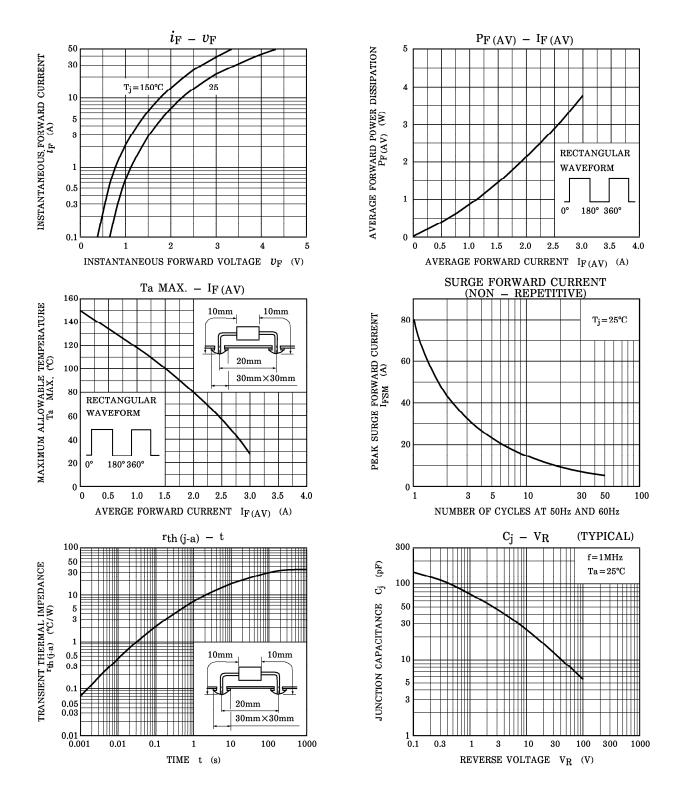
OUTPUT

Note 3: THERMAL RESISTANCE



961001EAA2

TOSHIBA is continually working to improve the quality and the reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to observe standards of safety, and to avoid situations in which a malfunction or failure of a TOSHIBA product could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent products specifications. Also, please keep in mind the precautions and conditions set forth in the TOSHIBA Semiconductor Reliability Handbook.



The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others. The information contained herein is subject to change without notice.